

• Product Summary

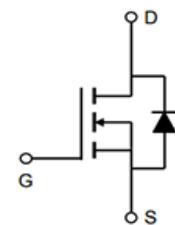
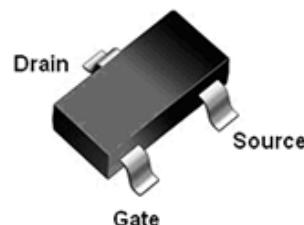
Part #	V _{DS}	R _{DS(on).typ} (@V _{GS} =10V)	R _{DS(on).typ} (@V _{GS} =4.5V)	I _D
EFM3442A	100V	514mΩ	530mΩ	1A

• Features

- Low R_{DS(on)} @V_{GS}=10V
- 4.5V Logic Level Control
- N Channel SOT23-3L Package
- Pb-Free, RoHS Compliant

• Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply
- Motor control


N-Channel MOSFET

HF
• Ordering Information:

Part NO.	EFM3442A
Marking	BC****
Packing Information	REEL TAPE
Basic ordering unit (pcs)	3000

• Absolute Maximum Ratings (T_C=25°C)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	1	A
Drain Current-Pulsed (Note 1)	I _{DM}	4	A
Maximum Power Dissipation	P _D	1.4	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 To 150	°C

• Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	100	°C/W
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• Static Electrical Characteristics @ $T_J = 25^\circ C$ (unless otherwise stated)

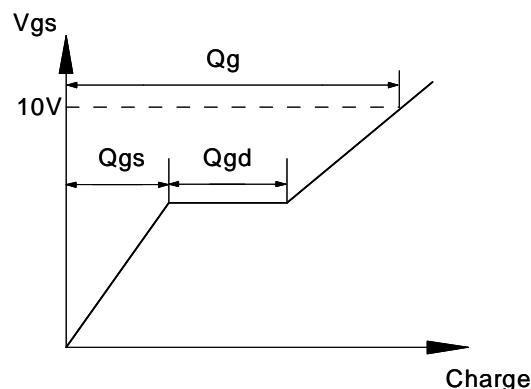
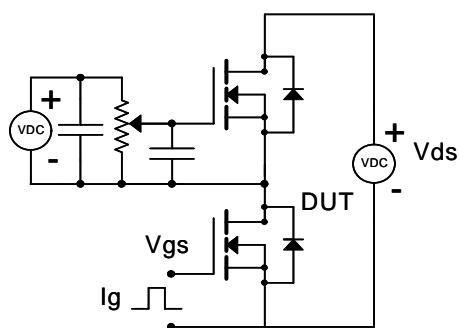
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	V_{DSS}	$V_{GS}=0V I_D=250\mu A$	100	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=100V V_{GS}=0V$	--	--	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V V_{DS}=0V$	--	--	± 100	nA
On Characteristics <small>(Note 3)</small>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS} I_D=250\mu A$	1.0	1.6	2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V I_D=1A$	--	514	528	$m\Omega$
		$V_{GS}=4.5V I_D=1A$	--	530	550	$m\Omega$
Dynamic Characteristics <small>(Note 4)</small>						
Input Capacitance	C_{iss}	$V_{DS}=50V V_{GS}=0V$ $F=1.0MHz$	--	100	--	PF
Output Capacitance	C_{oss}		--	13	--	PF
Reverse Transfer Capacitance	C_{rss}		--	5	--	PF
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=1A$	--	2.8	--	S
Switching Characteristics <small>(Note 4)</small>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=50V I_D=1A$ $V_{GS}=10V R_G=3\Omega$	--	5	--	nS
Turn-on Rise Time	t_r		--	4	--	nS
Turn-Off Delay Time	$t_{d(off)}$		--	12	--	nS
Turn-Off Fall Time	t_f		--	5	--	nS
Total Gate Charge	Q_g	$V_{DS}=50V I_D=1A$ $V_{GS}=10V$	--	2.8	--	nC
Gate-Source Charge	Q_{gs}		--	0.4	--	nC
Gate-Drain Charge	Q_{gd}		--	0.8	--	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage <small>(Note 3)</small>	V_{SD}	$V_{GS}=0V I_S=1A$	--	0.79	1.2	V
Diode Forward Current <small>(Note 2)</small>	I_S		--	--	1	A

Notes:

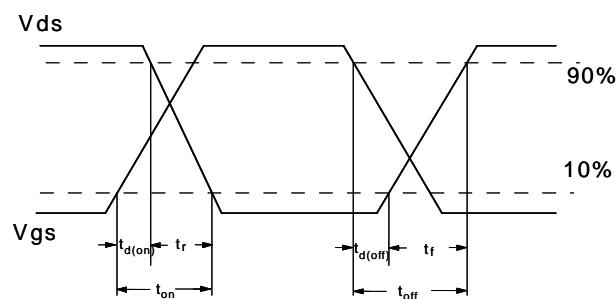
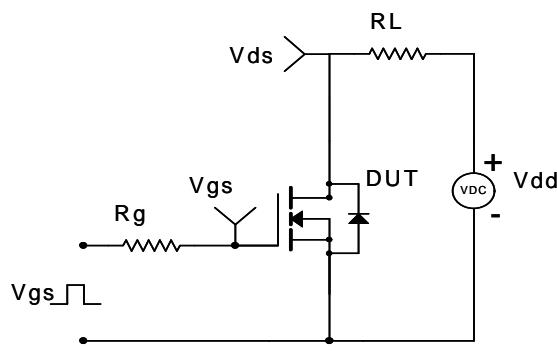
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production

• Test Circuit

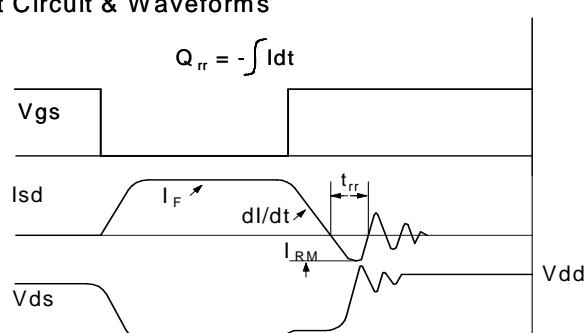
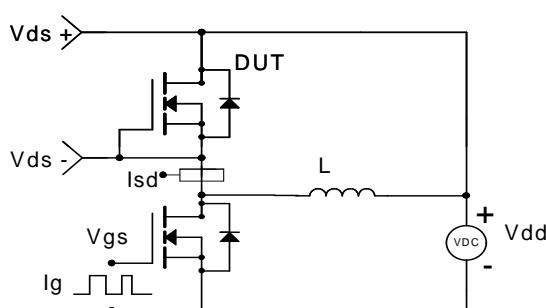
Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms



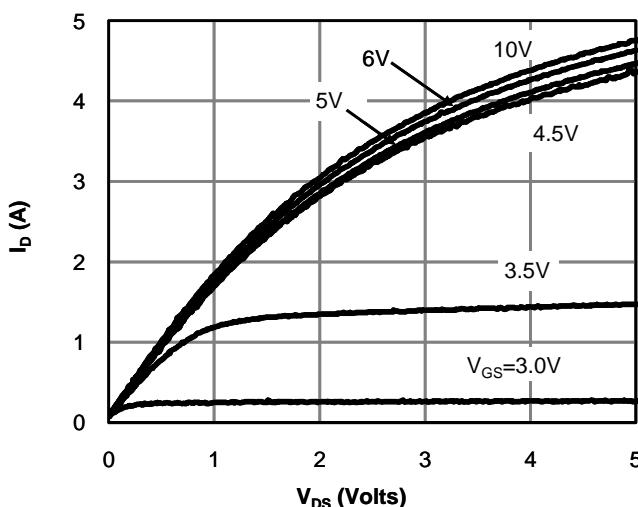
• Typical Characteristics


Fig 1: On-Region Characteristics (Note E)

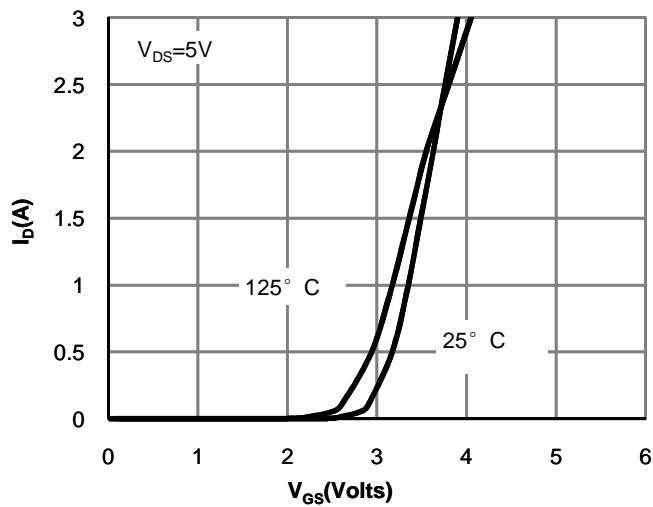


Figure 2: Transfer Characteristics (Note E)

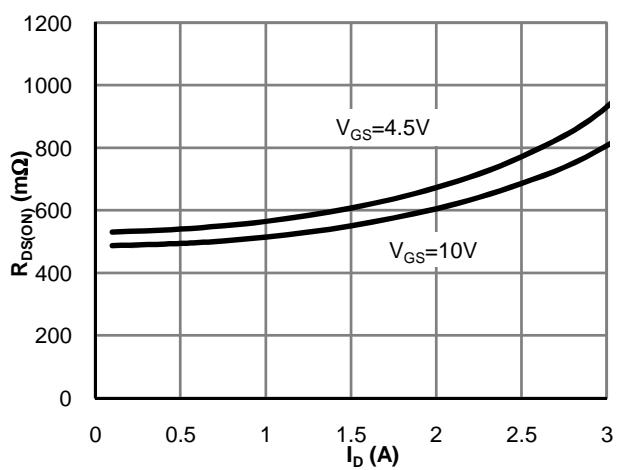


Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

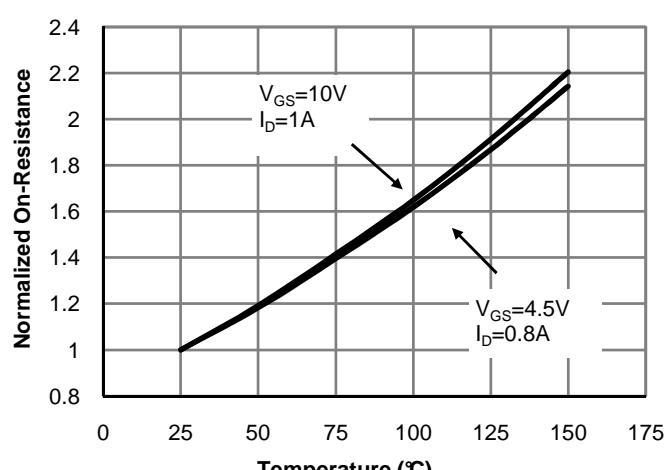


Figure 4: On-Resistance vs. Junction Temperature (Note E)

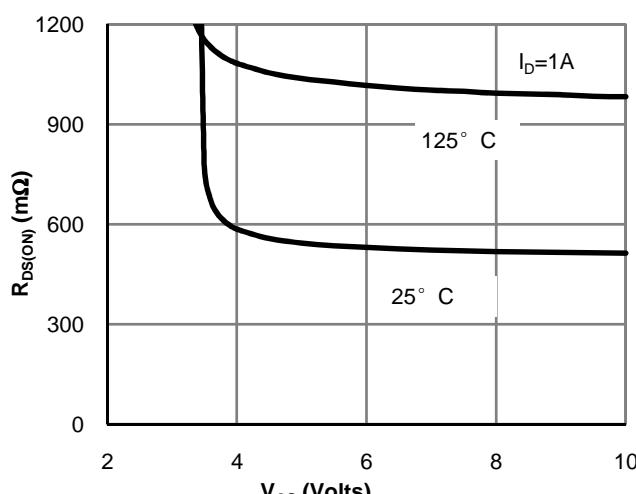


Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

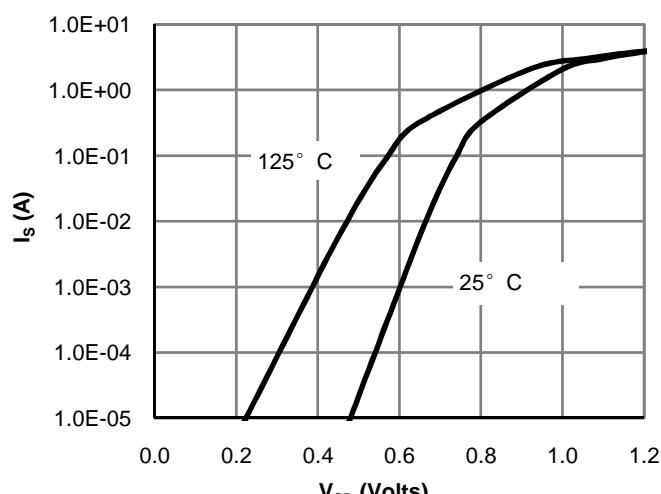


Figure 6: Body-Diode Characteristics (Note E)

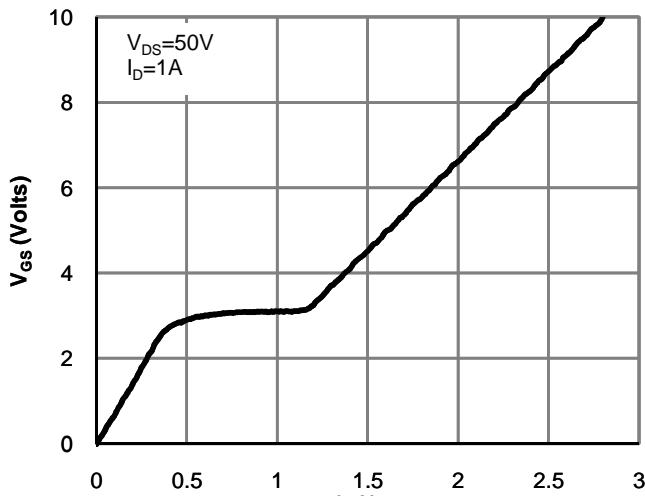


Figure 7: Gate-Charge Characteristics

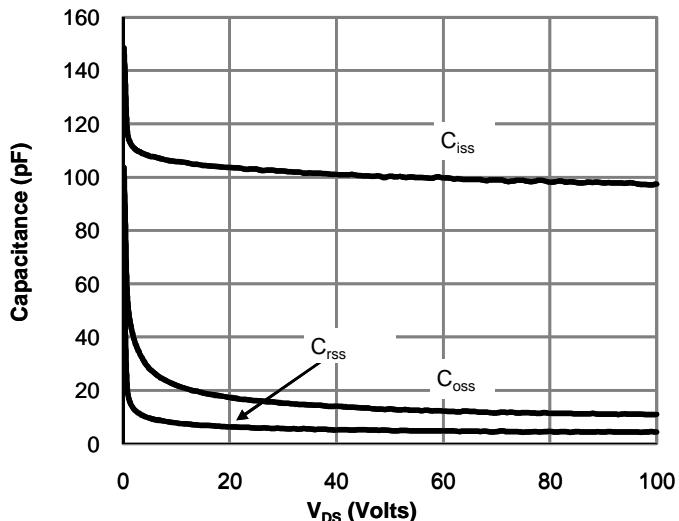


Figure 8: Capacitance Characteristics

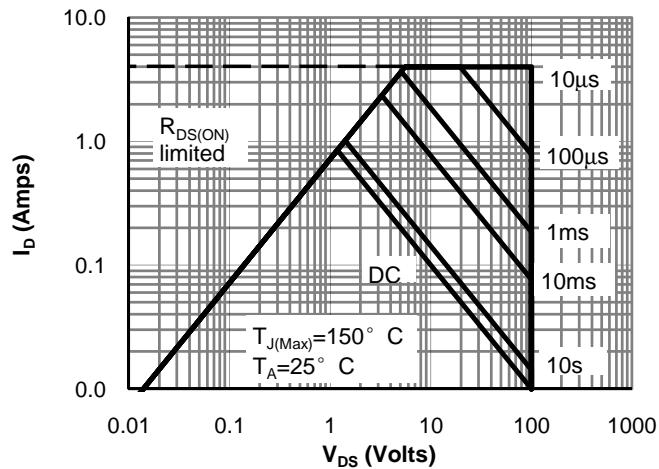


Figure 9: Maximum Forward Biased Safe Operating Area (Note F)

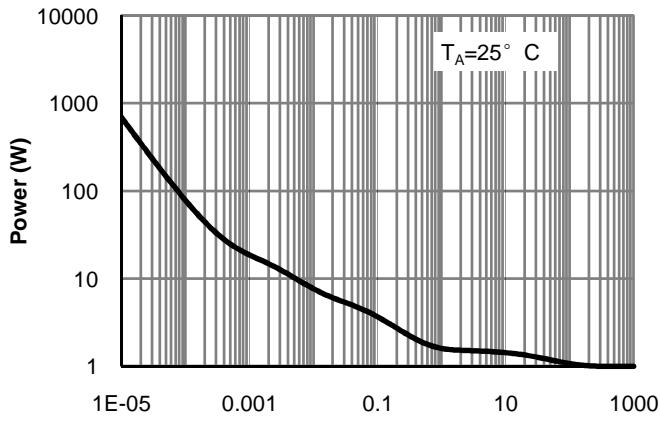


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note F)

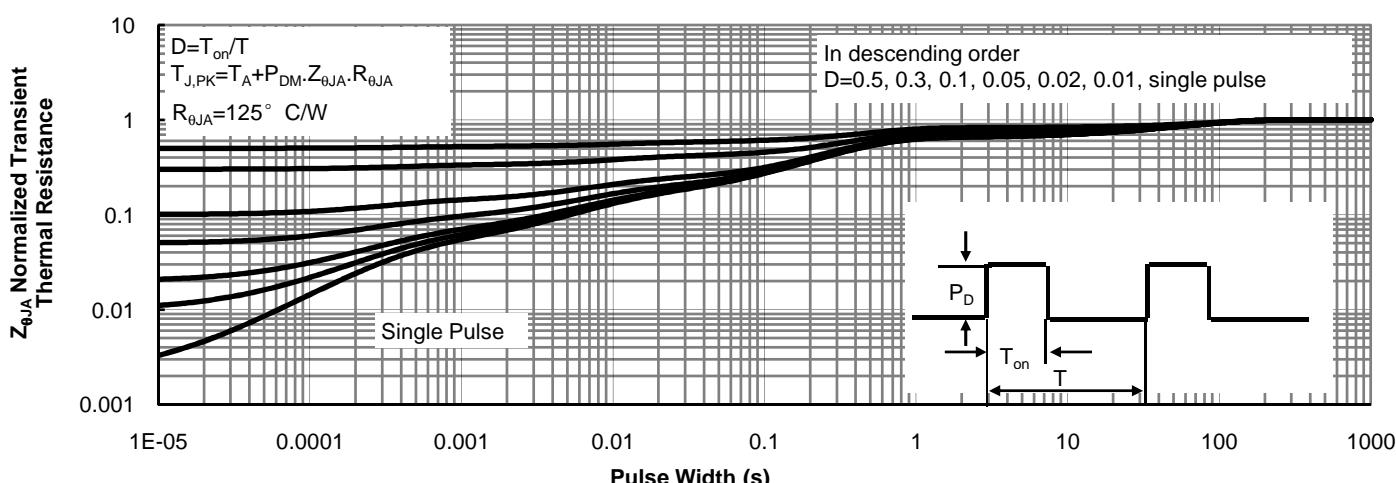
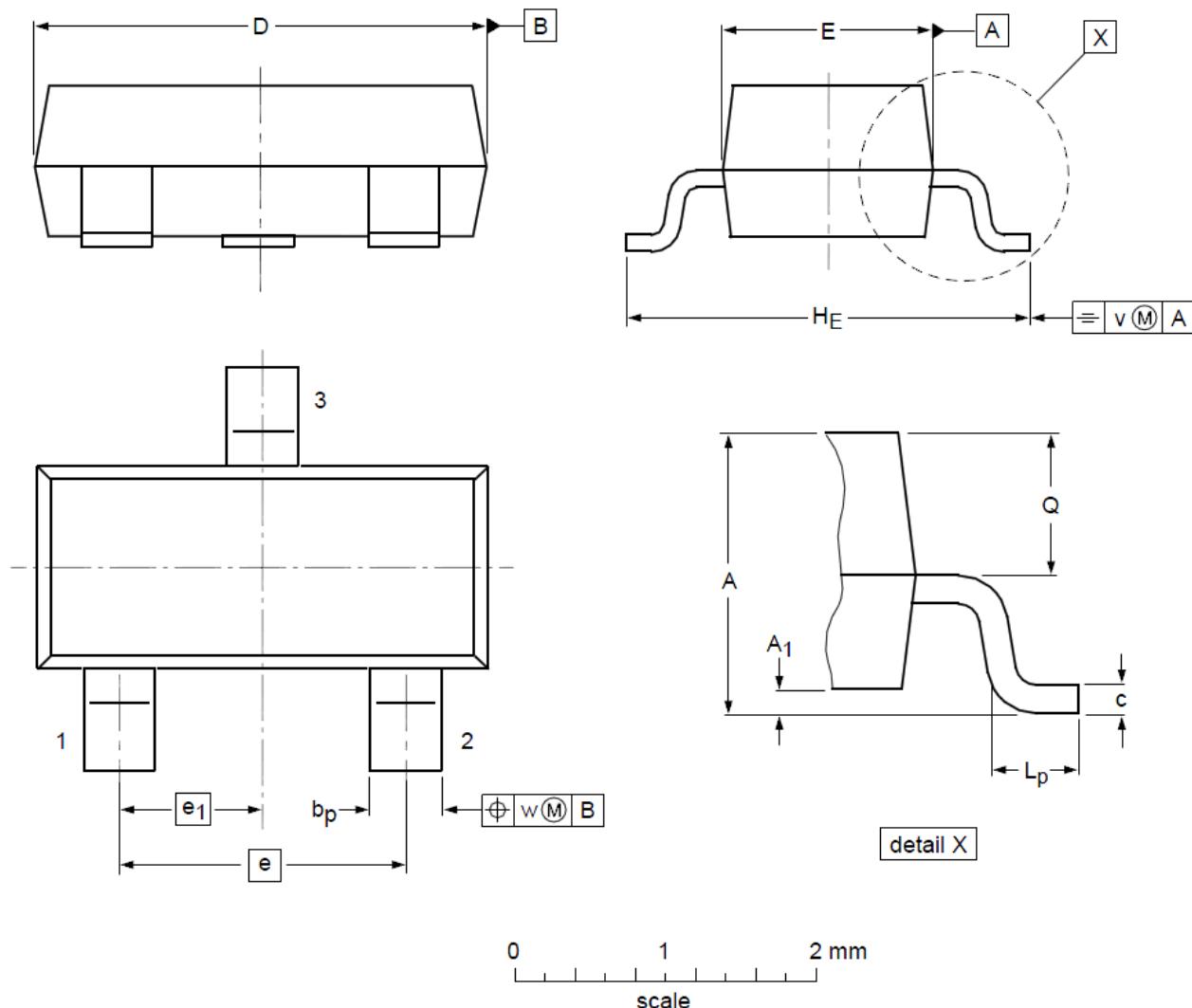


Figure 11: Normalized Maximum Transient Thermal Impedance (Note F)

SOT23-3L Package Outline Dimensions

DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	1.00	1.17	1.30	A₁	0.01	0.05	0.10
b_p	0.35	0.39	0.50	c	0.10	0.20	0.26
D	2.70	2.90	3.10	E	1.30	1.58	1.70
e	--	1.90	--	e₁	--	0.95	--
H_E	2.50	2.78	3.00	L_p	0.20	0.32	0.60
Q	0.23	0.27	0.33	v	--	0.20	--
w	--	0.20	--				